Docker No.: GR 98 P 1379 D

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By: On P.

Date: 8/6/01

## IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

Applicant : Lars-Peter Heineck et al.

Applic. No. : 09/885,553 Filed : June 20, 2001

Title : MOS Transistor in a Single-Transistor Memory Cell Having

a Locally Thickened Gate Oxide

Art Unit : 2814

## INFORMATION DISCLOSURE STATEMENT

Hon. Commissioner of Patents and Trademarks, Washington, D.C. 20231

Sir:

In accordance with 37 C.F.R. 1.98 copies of the following patents and/or publications are submitted herewith:

United States Patent No. 5,382,533 (Ahmad et al.), dated January 17, 1995;

United States Patent No. 5,679,968 (Smayling et al.), dated October 21, 1997;

United States Patent No. 5,714,413 (Brigham et al.), dated February 3, 1998;

European Patent Application EP 0 621 632 A1 (Rajeevakumar et al.), dated October 26, 1994.

If no translation of pertinent portions of any foreign language patents or publications mentioned above is included with the aforementioned copies of those applications,

patents and/or publications, it is because no existing translation is readily available to the applicant.

Respectfully submitted.

For Applicants

Mark P. Weichselbaum Reg. No. 43,248

Date: August 6, 2001

Lerner And Greenberg, P.A. Post Office Box 2480 Hollywood, FL 33022-2480 Tel: (954) 925-1100 Fax: (954) 925-1101

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U.S. DEPARTMENT OF COMMERCE
PATENT AND TRADEMARK OFFICE

DEPARTMENT OF COMMERCE

Attorney Docket No.:
GR 98 P 1379 D

INFORMATION DISCLOSURE STATEMENT BY APPLICANT

(37 CFR 1.98(b))

No.: Applic. No. 0 D 09/885.553

Applicant

Lars-Peter Heineck et al.

Filing Date G

Group Art Unit 2814

## U.S. PATENT DOCUMENTS

EXAMINER INITIALS		PATENT NO.	DATE	PATENTEE	CLASS	SUB CLASS	FILING DATE
W.	Α	5,382,533	01/17/95	Ahmad et al.			
gg.	В	5,679,968	10/21/97	Smayling et al.			
300	С	5,714,413	02/03/98	Brigham et al.			
J	D						
	E						
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	G						
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## FOREIGN PATENT DOCUMENT

		DOCUMENT NO.	DATE	COUNTRY	CLASS	SUB CLASS	TRA YES	NSL. J NO
THE	J	0 621 632 A1	10/26/94	Europe				х
y	К							
	L							
	М							
	N							

OTHER DOCUMENTS (Including Author, Title, Date, Pertinent Pages, etc.)

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EXAMINER

DATE CONSIDERED

EXAMINER: Initial if citation considered, whether or not citation is in conformance with MPEP 609; Draw line through citation if not in conformance and not considered. Include copy of this form with next communication to applicant.